

YJ Planar Schottky Barrier Diode Die Specification

45V 30A, 158mil, Schottky barrier diode die based on silicon planar process
Part No.: PSB158M045SS-290E

Main Products Characteristics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 30\text{ A}$

2%

Device Schematics and Outline Drawing

Die Thickness *

Die Size **